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2015 年 4 月

# FCD850N80Z / FCU850N80Z

## N- 沟道 SuperFET<sup>®</sup> II MOSFET

800 V, 6 A, 850 mΩ

### 特性

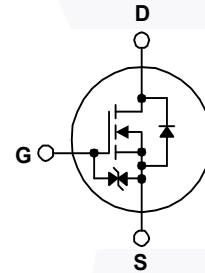
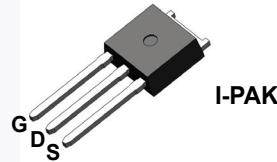
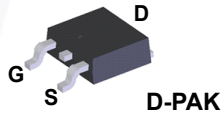
- 典型值  $R_{DS(on)} = 710 \text{ m}\Omega$  (典型值)
- 超低栅极电荷 (典型值  $Q_g = 22 \text{ nC}$ )
- 低  $E_{oss}$  (典型值  $2.3 \text{ uJ @ } 400 \text{ V}$ )
- 低有效输出电容 (典型值  $C_{oss(eff.)} = 106 \text{ pF}$ )
- 100% 经过雪崩测试
- 符合 RoHS 标准
- 增强的 ESD 能力

### 描述

SuperFET<sup>®</sup> II MOSFET 是飞兆利用电荷平衡技术实现出色的低导通电阻和更低栅极电荷性能的全新高压超级结 (SJ) MOSFET 系列产品。这项技术专用于最小化导通损耗并提供卓越的开关性能、dv/dt 额定值和更高雪崩能量。此外，内部栅源极 ESD 二极管允许经受超过 2 kV HBM 冲击压力。因此，SuperFET II MOSFET 非常适合功率开关应用，如音频、笔记本适配器、照明、ATX 电源和工业电源应用。

### 应用

- AC-DC 电源
- LED 照明



**最大绝对额定值**  $T_C = 25^\circ\text{C}$  除非另有说明。

符号	参数		FCD850N80Z FCU850N80Z	单位
$V_{DSS}$	漏极 - 源极电压		800	V
$V_{GSS}$	栅极 - 源极电压	- DC	$\pm 20$	V
		- AC ( $f > 1 \text{ Hz}$ )	$\pm 30$	
$I_D$	漏极电流	- 连续 ( $T_C = 25^\circ\text{C}$ )	6	A
		- 连续 ( $T_C = 100^\circ\text{C}$ )	3.8	
$I_{DM}$	漏极电流	- 脉冲 (注 1)	18	A
$E_{AS}$	单脉冲雪崩能量	(注 2)	114	mJ
$I_{AR}$	雪崩电流	(注 1)	1.2	A
$E_{AR}$	重复雪崩能量	(注 1)	0.284	mJ
dv/dt	MOSFET dv/dt		100	V/ns
	二极管恢复 dv/dt 峰值 (注 3)		20	
$P_D$	功耗	( $T_C = 25^\circ\text{C}$ )	75	$\Omega$
		- 高于 $25^\circ\text{C}$ 的功耗系数	0.6	$\text{W}/^\circ\text{C}$
$T_J, T_{STG}$	工作和存储温度范围		-55 至 +150	$^\circ\text{C}$
$T_L$	用于焊接的最大引脚温度，距离外壳 1/8"，持续 5 秒		300	$^\circ\text{C}$

### 热性能

符号	参数	FCD850N80Z FCU850N80Z	单位
$R_{\theta JC}$	结至外壳热阻最大值	1.65	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	结至环境热阻最大值	100	

FCD850N80Z / FCU850N80Z — N-沟道 SuperFET<sup>®</sup> II MOSFET

## 封装标识与订购信息

器件编号	顶标	封装	包装方法	卷尺寸	带宽	数量
FCD850N80Z	FCD850N80Z	DPAK	卷带	330 mm	16 mm	2500 颗
FCU850N80Z	FCU850N80Z	IPAK	塑料管	不适用	不适用	75 个

电气特性  $T_C = 25^\circ\text{C}$  除非另有说明。

符号	参数	测试条件	最小值	典型值	最大值	单位
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## 关断特性

$BV_{DSS}$	漏极-源极击穿电压	$V_{GS} = 0\text{ V}, I_D = 1\text{ mA}, T_J = 25^\circ\text{C}$	800	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	击穿电压温度系数	$I_D = 1\text{ mA}$ , 参考 $25^\circ\text{C}$ 数值	-	0.8	-	$\text{V}/^\circ\text{C}$
$I_{DSS}$	零栅极电压漏极电流	$V_{DS} = 800\text{ V}, V_{GS} = 0\text{ V}$	-	-	25	$\mu\text{A}$
		$V_{DS} = 640\text{ V}, V_{GS} = 0\text{ V}, T_C = 125^\circ\text{C}$	-	-	250	
$I_{GSS}$	栅极-体漏电流	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	-	-	$\pm 10$	$\mu\text{A}$

## 导通特性

$V_{GS(th)}$	栅极阈值电压	$V_{GS} = V_{DS}, I_D = 0.6\text{ mA}$	2.5	-	4.5	V
$R_{DS(on)}$	漏极至源极静态导通电阻	$V_{GS} = 10\text{ V}, I_D = 3\text{ A}$	-	710	850	$\text{m}\Omega$
$g_{FS}$	正向跨导	$V_{DS} = 20\text{ V}, I_D = 3\text{ A}$	-	3.5	-	S

## 动态特性

$C_{iss}$	输入电容	$V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	-	990	1315	$\text{pF}$
$C_{oss}$	输出电容		-	28	37	$\text{pF}$
$C_{rss}$	反向传输电容		-	0.74	-	$\text{pF}$
$C_{oss}$	输出电容	$V_{DS} = 480\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	-	15	-	$\text{pF}$
$C_{oss(eff.)}$	有效输出电容	$V_{DS} = 0\text{ V}$ 至 $480\text{ V}, V_{GS} = 0\text{ V}$	-	106	-	$\text{pF}$
$Q_{g(tot)}$	10 V 的栅极电荷总量	$V_{DS} = 640\text{ V}, I_D = 6\text{ A}, V_{GS} = 10\text{ V}$	-	22	29	$\text{nC}$
$Q_{gs}$	栅极-源极栅极电荷		-	5	-	$\text{nC}$
$Q_{gd}$	栅极-漏极“米勒”电荷		(注 4)	-	8.6	-
ESR	等效串联电阻	$f = 1\text{ MHz}$	-	2.4	-	$\Omega$

## 开关特性

$t_{d(on)}$	导通延迟时间	$V_{DD} = 400\text{ V}, I_D = 6\text{ A}, V_{GS} = 10\text{ V}, R_g = 4.7\ \Omega$	-	16	42	ns
$t_r$	开通上升时间		-	10	30	ns
$t_{d(off)}$	关断延迟时间		-	40	90	ns
$t_f$	关断下降时间		(注 4)	-	4.5	19

## 漏极-源极二极管特性

$I_S$	漏极-源极二极管最大正向连续电流	-	-	6	A	
$I_{SM}$	漏极-源极二极管最大正向脉冲电流	-	-	18	A	
$V_{SD}$	漏极-源极二极管正向电压	$V_{GS} = 0\text{ V}, I_{SD} = 6\text{ A}$	-	-	1.2	V
$t_{rr}$	反向恢复时间	$V_{GS} = 0\text{ V}, I_{SD} = 6\text{ A}, di_F/dt = 100\text{ A}/\mu\text{s}$	-	318	-	ns
$Q_{rr}$	反向恢复电荷		-	4.5	-	$\mu\text{C}$

## 注:

- 重复额定值: 脉冲宽度受限于最大结温。
- $I_{AS} = 1.2\text{ A}, V_{DD} = 50\text{ V}, R_G = 25\ \Omega$ , 开始于  $T_J = 25^\circ\text{C}$
- $I_{SD} \leq 6\text{ A}, di/dt \leq 200\text{ A}/\mu\text{s}, V_{DD} \leq BV_{DSS}$ , 开始于  $T_J = 25^\circ\text{C}$
- 典型特性本质上独立于工作温度。

## 典型性能特征

图 1. 导通区域特性

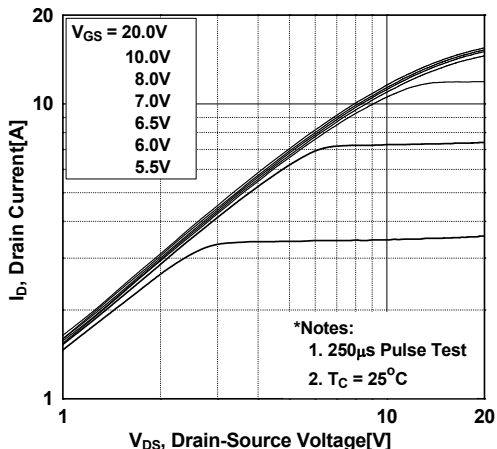


图 2. 传输特性

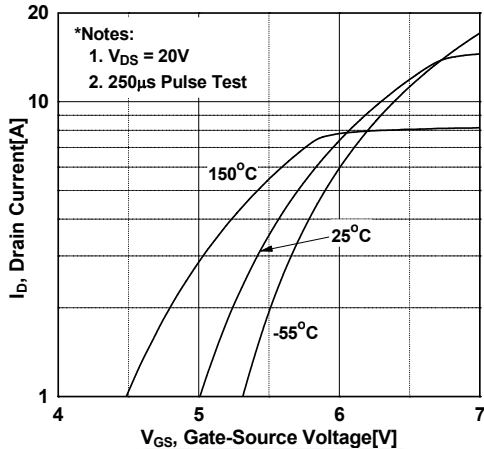


图 3. 导通电阻变化与漏极电流和栅极电压的关系

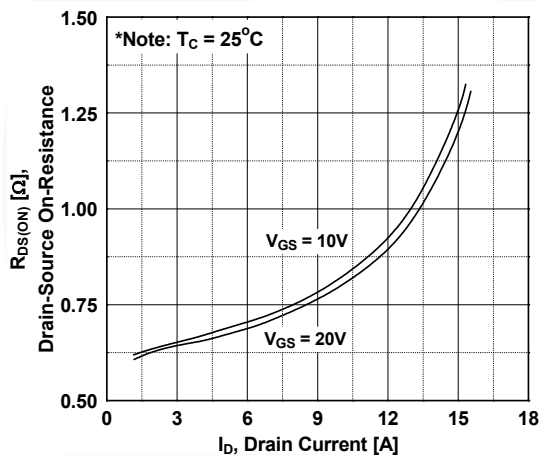


图 4. 体二极管正向电压变化与源极电流和温度的关系

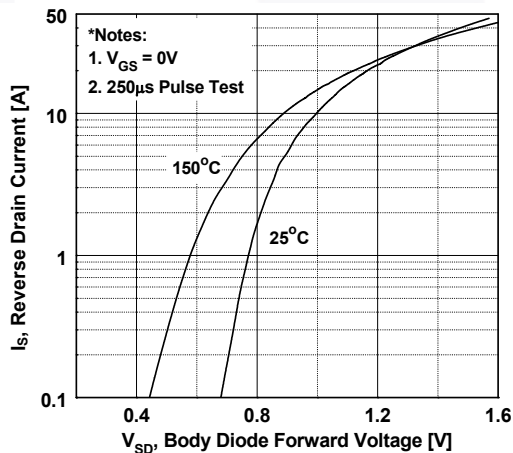


图 5. 电容特性

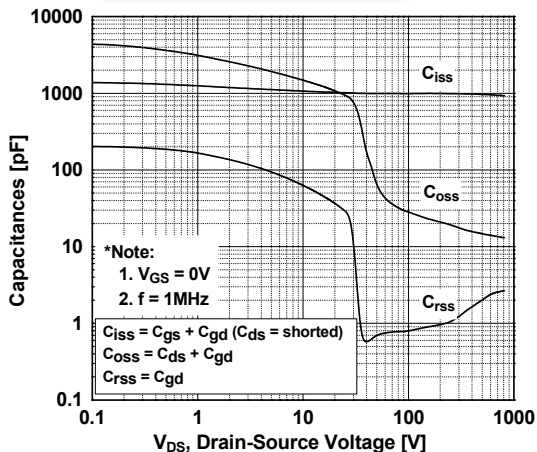
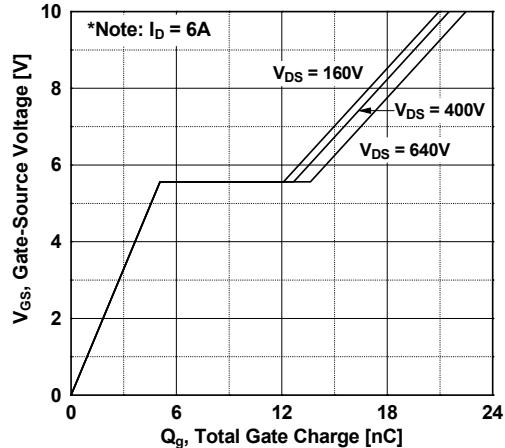


图 6. 栅极电荷特性



典型性能特征 (接上页)

图 7. 击穿电压变化与温度的关系

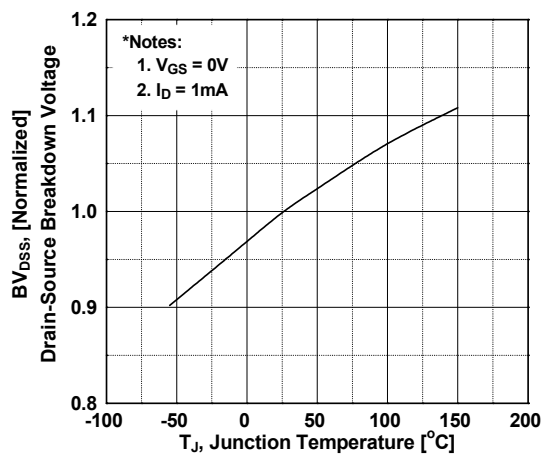


图 8. 导通电阻变化与温度的关系

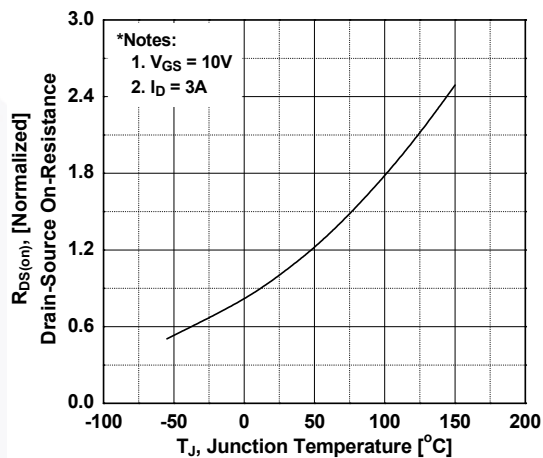


图 9. 最大安全工作区

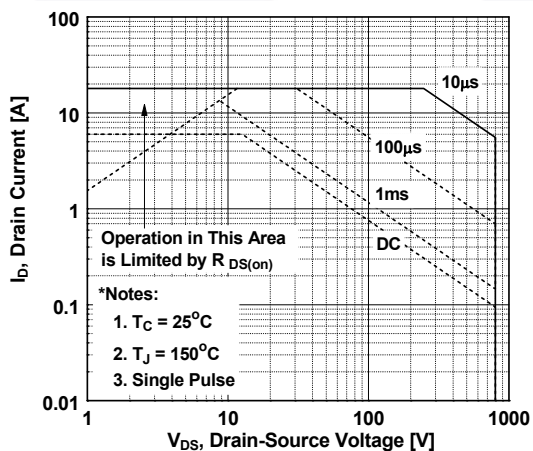


图 10. 最大漏极电流与壳温的关系

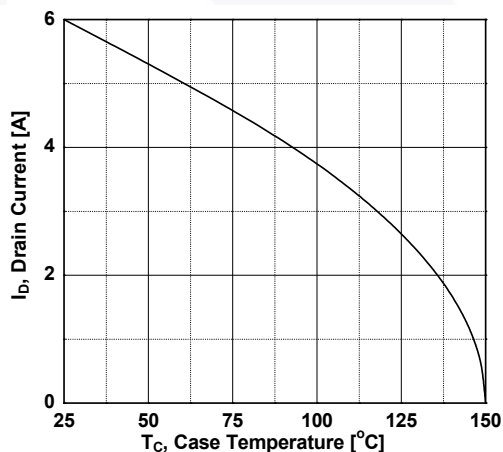
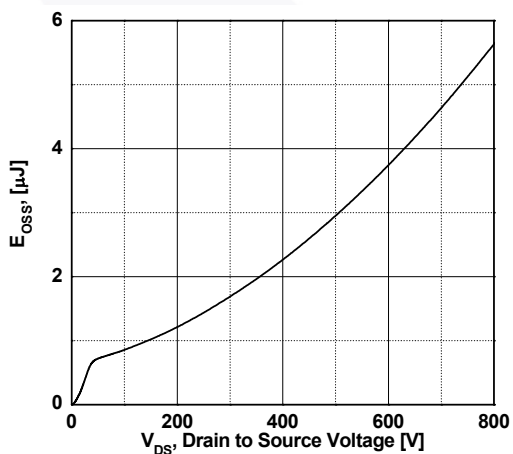
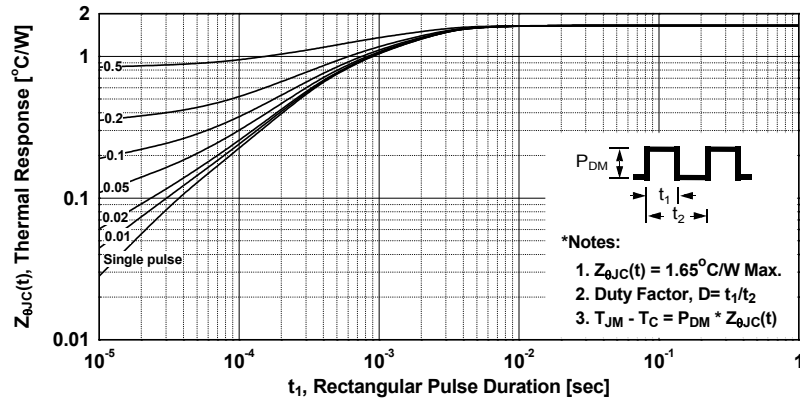


图 11. E\_oss 与漏源极电压的关系



典型性能特征 (接上页)

图 12. 瞬态热响应曲线



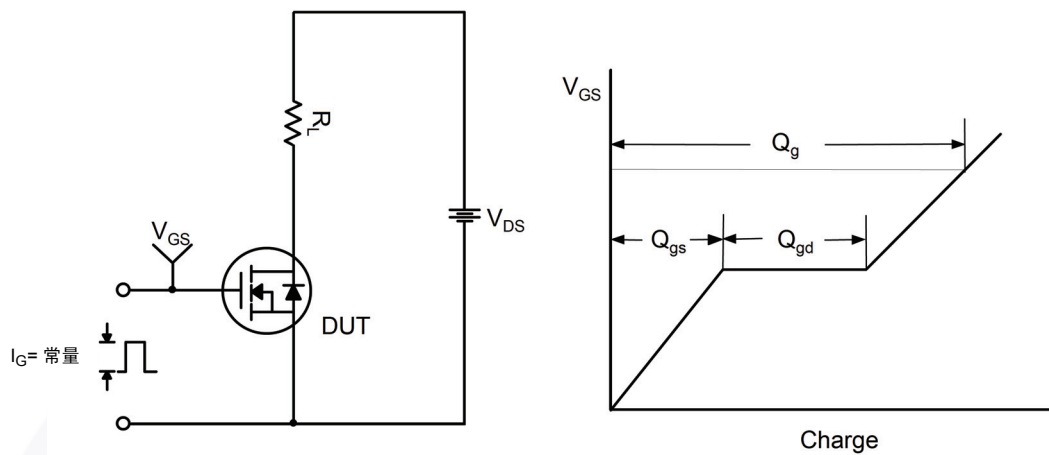


图 13. 栅极电荷测试电路与波形

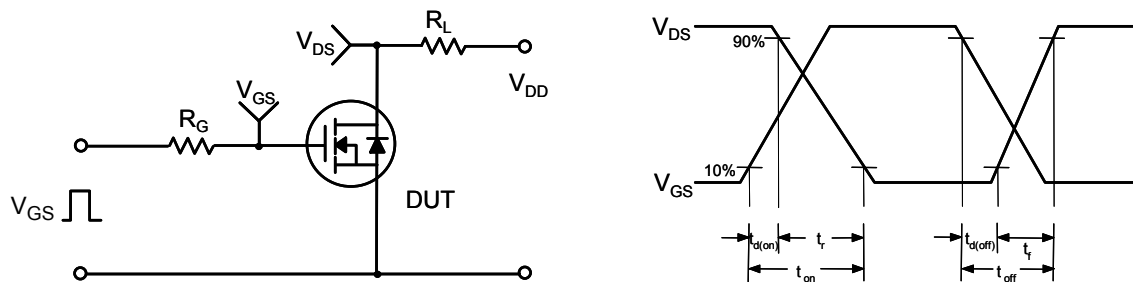


图 14. 阻性开关测试电路与波形

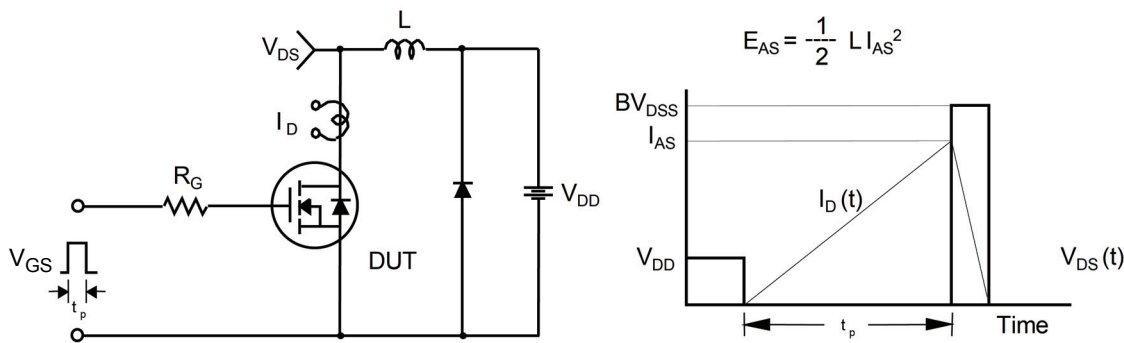


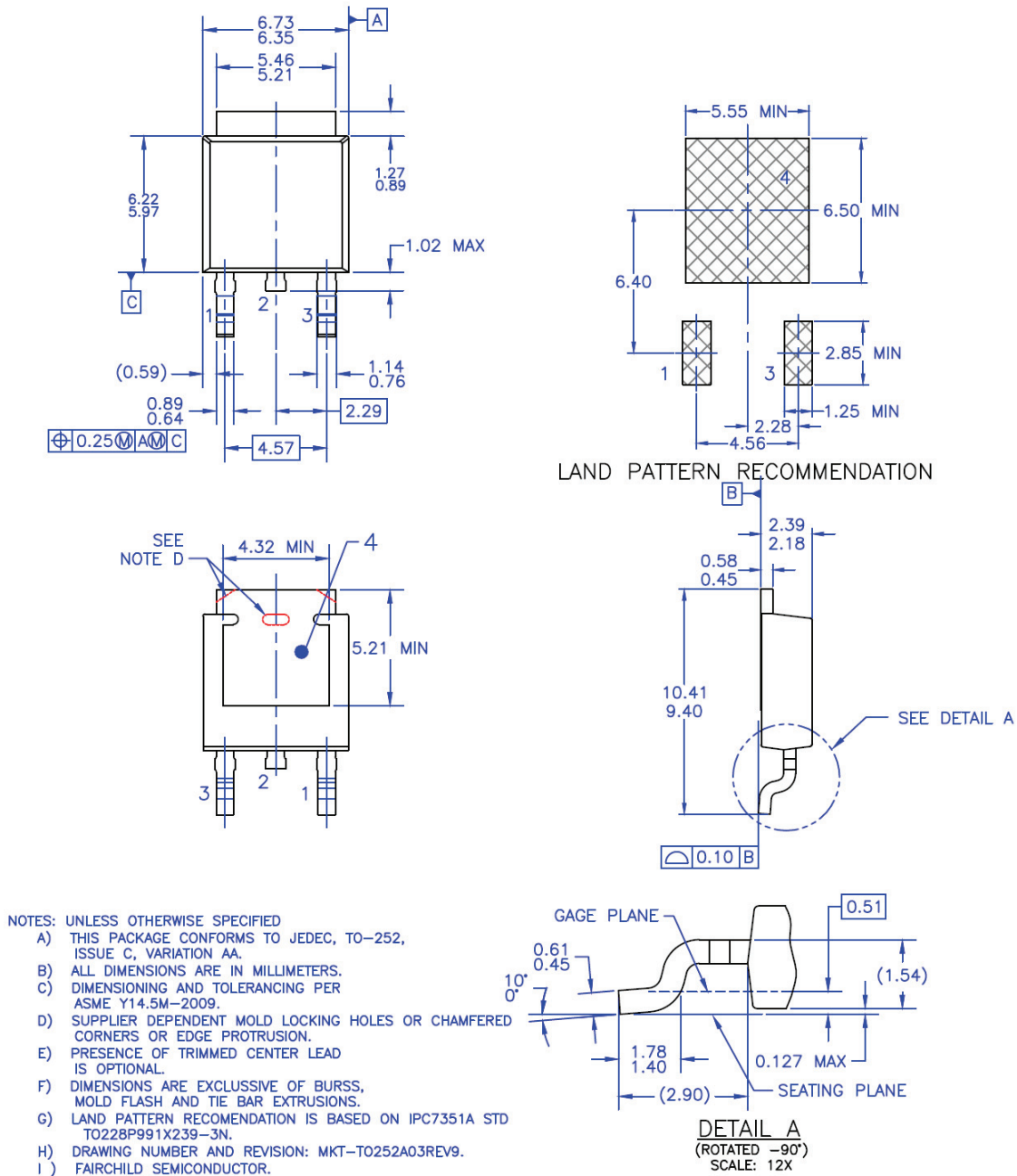
图 15. 非箝位电感开关测试电路与波形



图 16. 二极管恢复  $dv/dt$  峰值测试电路与波形



## 机械尺寸



**图 17. TO252 (D-PAK), 模塑 3 引脚, Jedec 变体 AA&AB**

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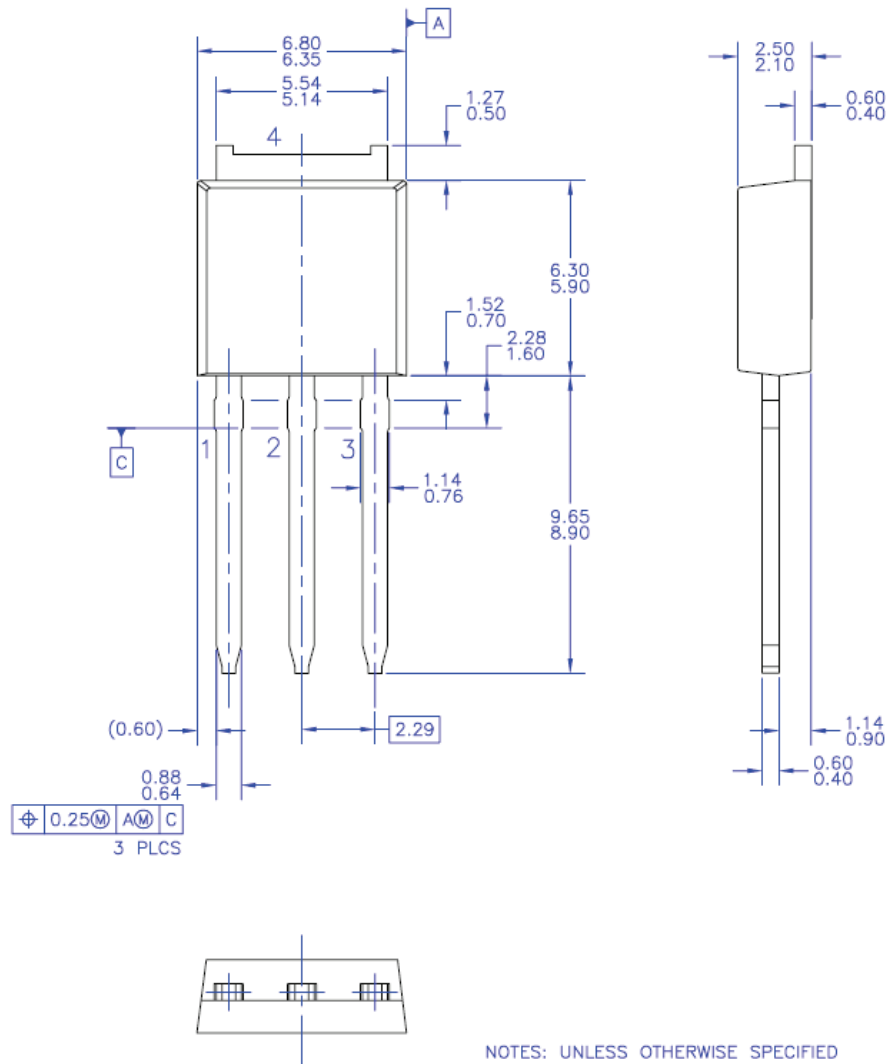


图 18. TO251 (I-PAK), 模塑 3 引脚, 变体 AA

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| BitSiC™                  | Global Power ResourceSM                         | Programmable Active Droop™  | TinyBoost®       |
| Build it Now™            | GreenBridge™                                    | QFET®                       | TinyBuck®        |
| CorePLUS™                | Green FPS™                                      | QS™                         | TinyCalc™        |
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| CTL™                     | GTO™  | SMART START™                | TinyPower™       |
| Current Transfer Logic™  | IntelliMAX™                                     | Solutions for Your Success™ | TinyPWM™         |
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